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Docket No.: 4539-0116PUS1  
(PATENT)

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re Patent Application of:  
Ken NAKANISHI

International Application No.: PCT/JP2005/001740

Application No.: NEW

Art Unit: N/A

Filed: August 1, 2006

Examiner: Not Yet Assigned

For: ION DOPING APPARATUS, ION DOPING  
METHOD, SEMICONDUCTOR DEVICE AND  
METHOD OF FABRICATING  
SEMICONDUCTOR DEVICE

**PRELIMINARY AMENDMENT**

MS Amendment  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Sir:

**INTRODUCTORY COMMENTS**

The following preliminary amendments and remarks are respectfully submitted in connection with the above-identified application.

This amendment includes:

**Amendments to the Claims** are reflected in the listing of claims which begins on page 2 of this paper.

**Remarks/Arguments** begin on page 7 of this paper.